

VEC2415

Power MOSFET 60V, 80mΩ, 3A, Dual N-Channel

This Power MOSFET is produced using ON Semiconductor's trench technology, which is specifically designed to minimize gate charge and low on resistance. This device is suitable for applications with low gate charge driving or low on resistance requirements.

Features

- Low On-Resistance
- 4V drive
- Low-Profile Package
- ESD Diode-Protected Gate
- Pb-Free and RoHS compliance
- Halogen Free compliance : VEC2415-TL-W

Typical Applications

- Motor Driver
- DC/DC Converter

SPECIFICATIONS

ABSOLUTE MAXIMUM RATING at Ta = 25°C (Note 1)

Parameter	Symbol	Value	Unit
Drain to Source Voltage	VDSS	60	V
Gate to Source Voltage	VGSS	±20	V
Drain Current (DC)	ID	3	A
Drain Current (Pulse) PW ≤ 10μs, duty cycle ≤ 1%	IDP	12	A
Power Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm) 1unit	PD	0.9	W
Total Dissipation When mounted on ceramic substrate (900mm ² × 0.8mm)	PT	1.0	W
Junction Temperature	Tj	150	°C
Storage Temperature	Tstg	-55 to +150	°C

Note 1 : Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Value	Unit
Junction to Ambient When mounted on ceramic substrate (900mm ² × 0.8mm) 1unit	RθJA	138.8	°C/W

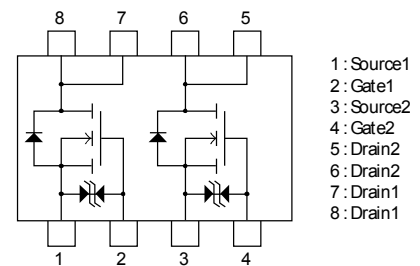


ON Semiconductor®

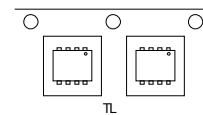
www.onsemi.com

VDSS	RDS(on) Max	ID Max
60V	80mΩ@ 10V	3A
	106mΩ@ 4.5V	
	116mΩ@ 4V	

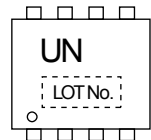
ELECTRICAL CONNECTION N-Channel



PACKING TYPE : TL



MARKING



ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

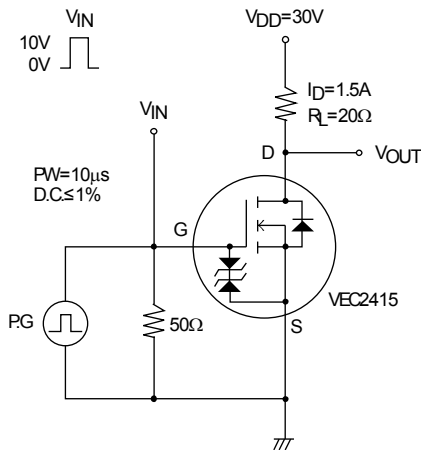
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ELECTRICAL CHARACTERISTICS at Ta = 25°C (Note 2)

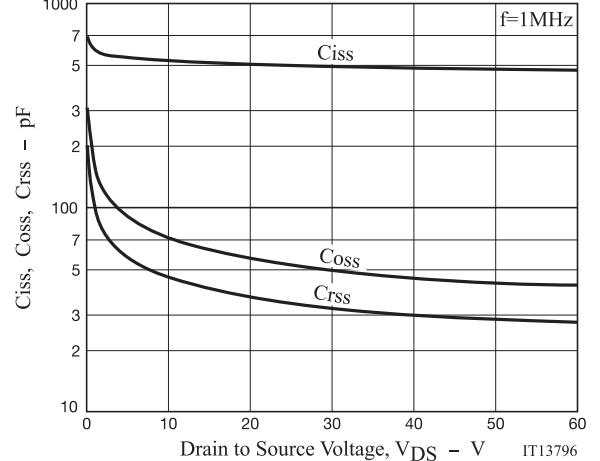
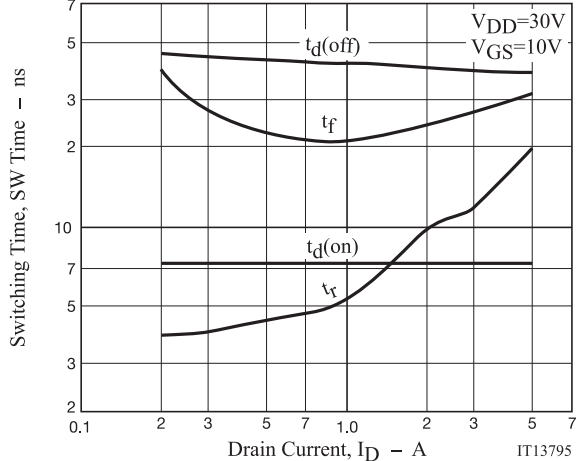
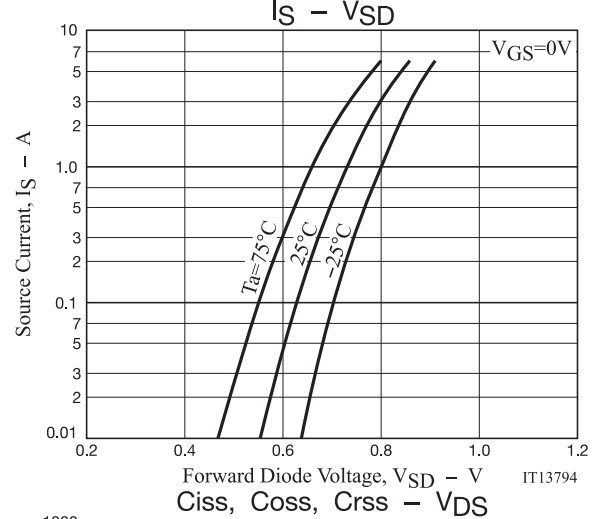
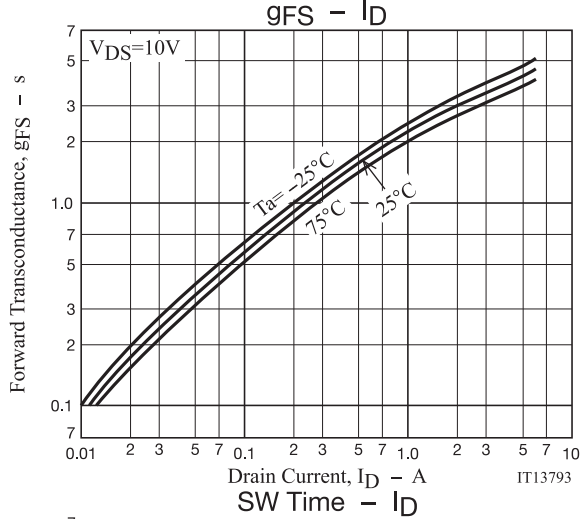
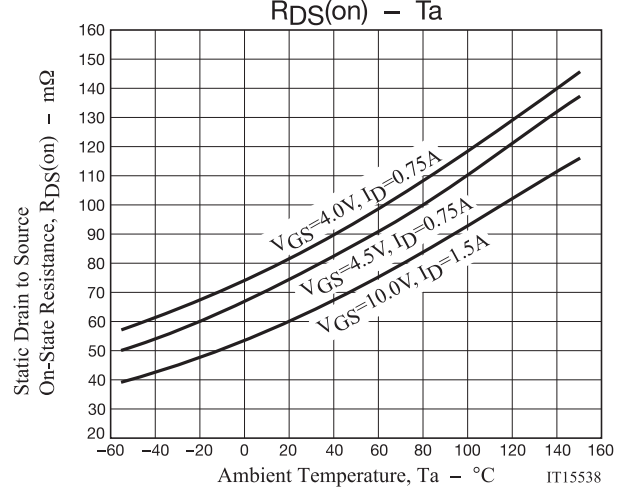
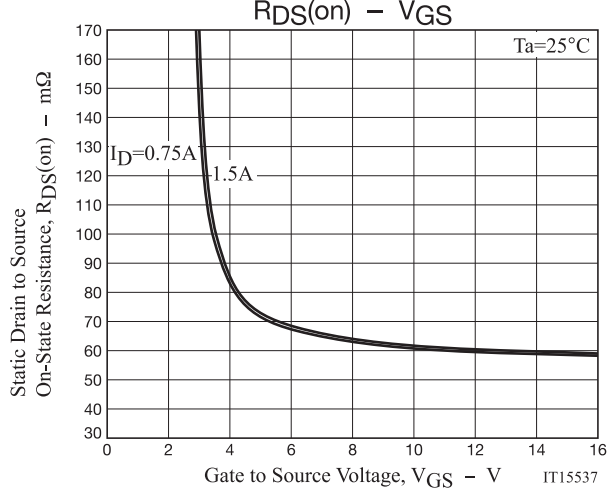
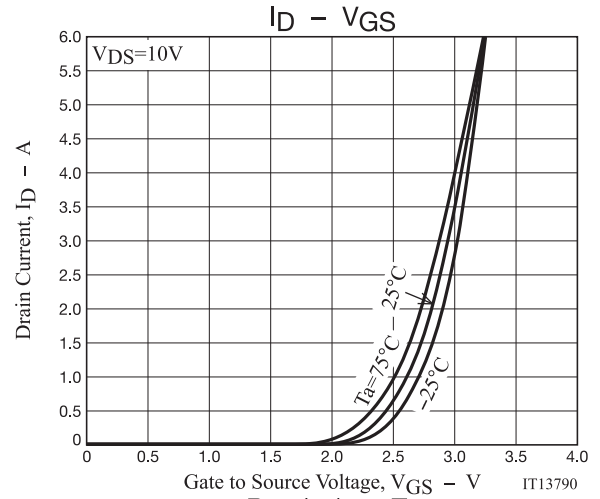
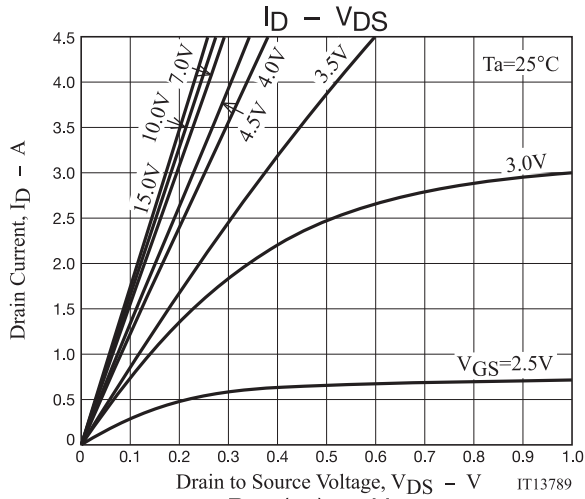
Parameter	Symbol	Conditions	Value			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	60			V
Zero-Gate Voltage Drain Current	IDSS	VDS=60V, VGS=0V			1	μA
Gate to Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Gate Threshold Voltage	VGS(th)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transconductance	gFS	VDS=10V, ID=1.5A		2.6		S
Static Drain to Source On-State Resistance	RDS(on)1	ID=1.5A, VGS=10V		62	80	mΩ
	RDS(on)2	ID=0.75A, VGS=4.5V		76	106	mΩ
	RDS(on)3	ID=0.75A, VGS=4V		83	116	mΩ
Input Capacitance	Ciss	VDS=20V, f=1MHz		505		pF
Output Capacitance	Coss			57		pF
Reverse Transfer Capacitance	Crss			37		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit		7.3		ns
Rise Time	tr			7.5		ns
Turn-OFF Delay Time	td(off)			41		ns
Fall Time	tf			22		ns
Total Gate Charge	Qg	VDS=30V, VGS=10V, ID=3A		10		nC
Gate to Source Charge	Qgs			1.6		nC
Gate to Drain "Miller" Charge	Qgd			2.1		nC
Forward Diode Voltage	VSD	IS=3A, VGS=0V		0.81	1.2	V

Note 2 : Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted.
Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

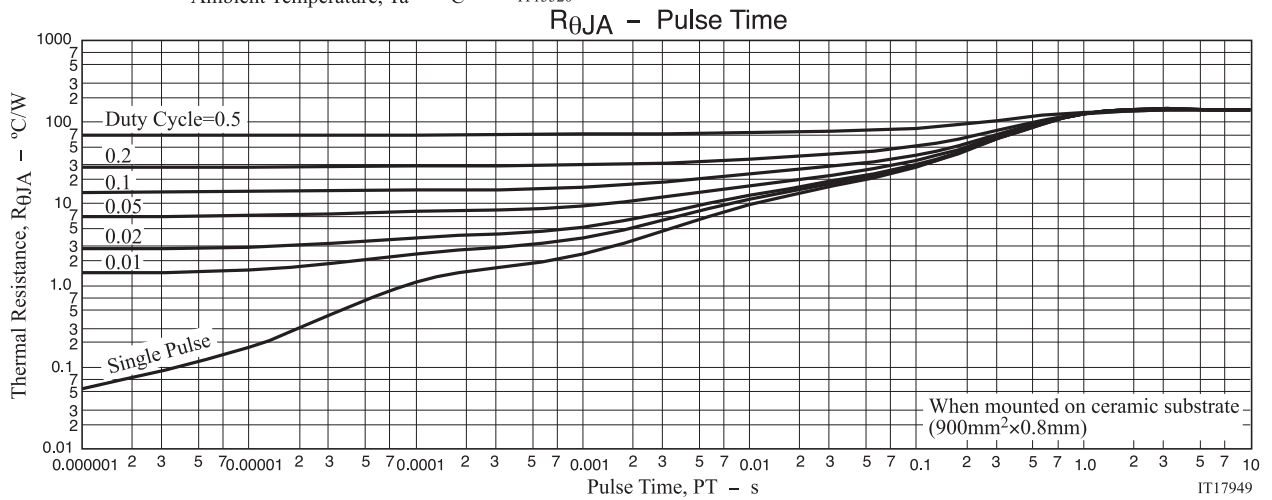
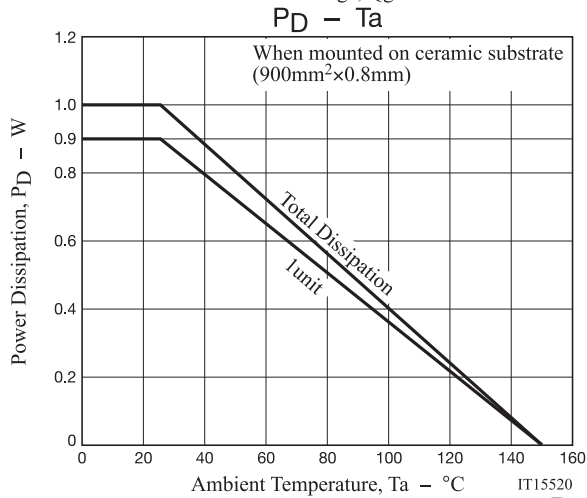
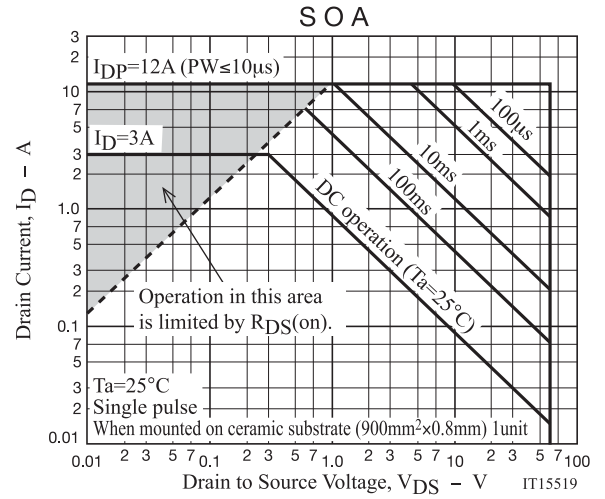
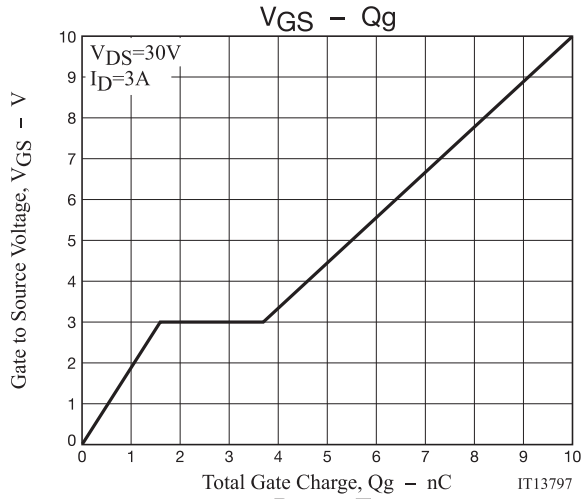
Switching Time Test Circuit



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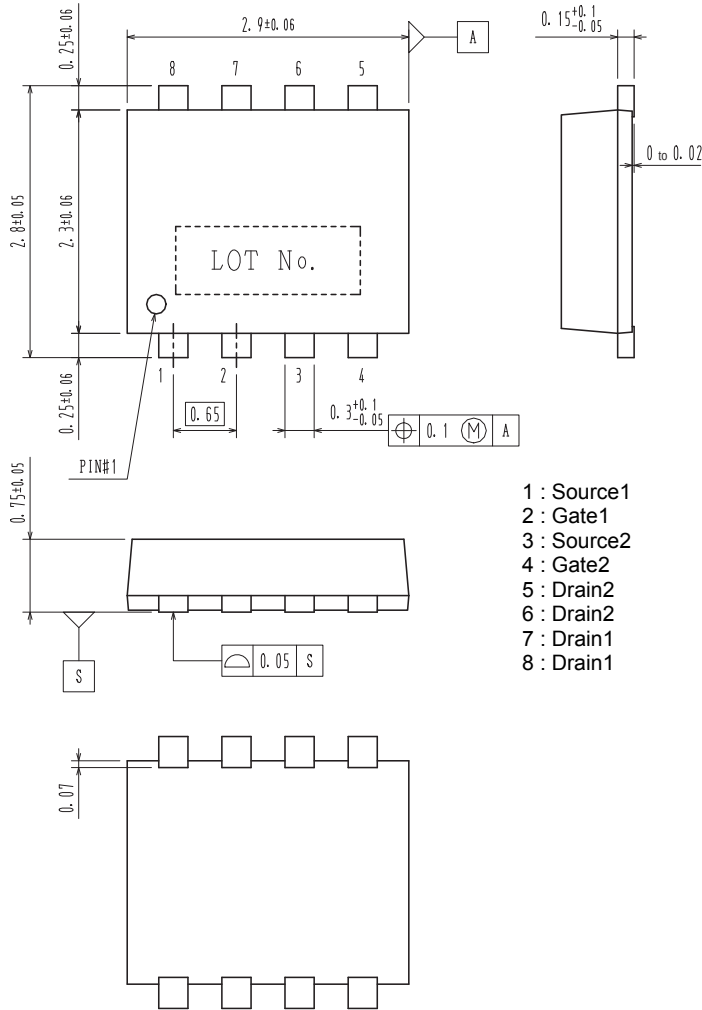


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PACKAGE DIMENSIONS

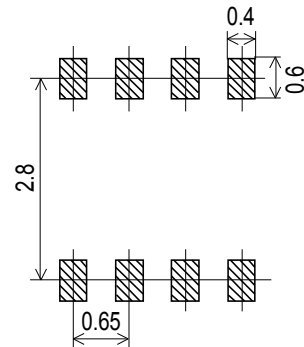
unit : mm

SOT-28FL / VEC8
CASE 318AH
ISSUE O



- 1 : Source1
- 2 : Gate1
- 3 : Source2
- 4 : Gate2
- 5 : Drain2
- 6 : Drain2
- 7 : Drain1
- 8 : Drain1

Recommended Soldering Footprint



ORDERING INFORMATION

Device	Marking	Package	Shipping (Qty / Packing)
VEC2415-TL-E	UN	SOT-28FL / VEC8 (Pb-Free)	3,000 / Tape & Reel
VEC2415-TL-W		SOT-28FL / VEC8 (Pb-Free / Halogen Free)	

† For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. http://www.onsemi.com/pub_link/Collateral/BRD8011-D.PDF

Note on usage : Since the VEC2415 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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